# FDD6530A

March 2015

FAIRCHILD. FDD6530A

# 20V N-Channel PowerTrench<sup>®</sup> MOSFET

# **General Description**

This N-Channel MOSFET has been designed specifically to improve the overall efficiency of DC/DC converters using either synchronous or conventional switching PWM controllers. It has been optimized for low gate charge, low RDS( ON) and fast switching speed.

# Applications

- DC/DC converter
- Motor drives

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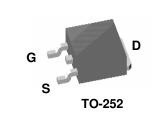
Features

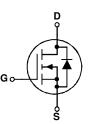
• 21 A, 20 V

- Low gate charge (6.5 nC typical)
- Fast switching
- + High performance trench technology for extremely low  $R_{\text{DS}(\text{ON})}$

 $R_{DS(ON)} = 32 \text{ m}\Omega @ V_{GS} = 4.5 \text{ V}$ 

 $R_{DS(ON)} = 47 \text{ m}\Omega @ V_{GS} = 2.5 \text{ V}$ 





### Absolute Maximum Ratings T<sub>A=25°C</sub> unless otherwise noted

Symbol	Parameter		Ratings	Units
V <sub>DSS</sub>	Drain-Source Voltage		20	V
V <sub>GSS</sub>	Gate-Source Voltage		±8	V
I <sub>D</sub>	Drain Current – Continuous	(Note 3)	21	А
	– Pulsed	(Note 1a)	100	
P <sub>D</sub>	Power Dissipation	(Note 1)	33	W
		(Note 1a)	3.3	
		(Note 1b)	1.6	
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Junction Temperature Range		-55 to +175	°C

### **Thermal Characteristics**

$R_{\theta JC}$	Thermal Resistance, Junction-to-Case	(Note 1)	4.5	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	(Note 1a)	45	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	(Note 1b)	96	°C/W

# Package Marking and Ordering Information

Device Marking	Device	Reel Size	Tape width	h Quantity	
FDD6530A	FDD6530A	13"	16mm 2		
	•			•	

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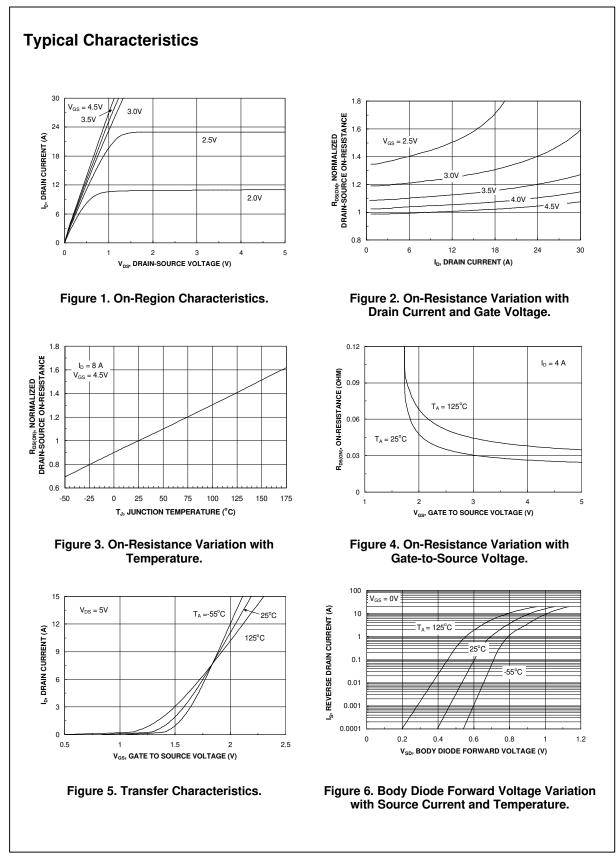
	Parameter	Test Conditions	Min	Тур	Max	Units
Drain-So	ource Avalanche Ratings (Note	e 2)	•			
W <sub>DSS</sub>	Drain-Source Avalanche Energy	Single Pulse, $V_{DD} = 10 V$			55	mJ
AR	Drain-Source Avalanche Current				8	А
Off Char	acteristics					
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	$V_{GS} = 0 V$ , $I_D = 250 \mu A$	20			V
<u>ΔBV<sub>DSS</sub></u> ΔT <sub>J</sub>	Breakdown Voltage Temperature Coefficient	$I_D = 250 \ \mu\text{A}$ , Referenced to $25^{\circ}\text{C}$		15		mV/°C
DSS	Zero Gate Voltage Drain Current	$V_{\text{DS}} = 16 \text{ V}, \qquad V_{\text{GS}} = 0 \text{ V}$			1	μA
GSSF	Gate-Body Leakage, Forward	$V_{\text{GS}} = 8 \text{ V}, \qquad V_{\text{DS}} = 0 \text{ V}$			100	nA
GSSR	Gate-Body Leakage, Reverse	$V_{\text{GS}} = -8 \ \text{V}, \qquad V_{\text{DS}} = 0 \ \text{V}$			-100	nA
On Char	acteristics (Note 2)					
/ <sub>GS(th)</sub>	Gate Threshold Voltage	$V_{\text{DS}} = V_{\text{GS}}, \qquad I_{\text{D}} = 250 \; \mu \text{A}$	0.4	0.9	1.2	V
$\Delta V_{GS(th)} \Delta T_J$	Gate Threshold Voltage Temperature Coefficient	$I_D = 250 \ \mu\text{A}$ , Referenced to $25^{\circ}\text{C}$		-3		mV/°C
R <sub>DS(on)</sub>	Static Drain-Source	$V_{GS} = 4.5 V, I_D = 8 A$		26	32	mΩ
	On-Resistance			36 36	47 48	
D(on)	On-State Drain Current	$V_{GS} = 4.5 \text{ V},  V_{DS} = 5 \text{ V}$	20			Α
FS	Forward Transconductance	$V_{DS} = 5 V$ , $I_D = 8 A$		21		S
Dynamic	Characteristics					
Ciss	Input Capacitance	$V_{DS} = 10 V$ , $V_{GS} = 0 V$ ,		710		pF
Coss	Output Capacitance	f = 1.0 MHz		173		pF
Crss Crss	Reverse Transfer Capacitance	-		84		pF
	g Characteristics (Note 2)			1	1	
	Turn–On Delay Time	$V_{DD} = 10 V$ , $I_{D} = 1 A$ ,		8	16	ns
d(on) r	Turn-On Rise Time	$V_{GS} = 4.5 V, R_{GEN} = 6$		7	14	ns
r d(off)	Turn-Off Delay Time			, 18	32	ns
а(оп) f	Turn-Off Fall Time	-		4	8	ns
י ג <sup>מ</sup>	Total Gate Charge	$V_{DS} = 10 \text{ V}, \qquad I_D = 8 \text{ A},$		6.5	9	nC
∽g ⊋ <sub>gs</sub>	Gate-Source Charge	$V_{GS} = 4.5 V$		1.3	Ŭ	nC
x <sub>gs</sub> Ω <sub>gd</sub>	Gate-Drain Charge	-		1.9		nC
	ource Diode Characteristics	and Maximum Batings			l	
s	Maximum Continuous Drain–Source				2.7	А
√ <sub>SD</sub>	Drain-Source Diode Forward Voltage	$V_{GS} = 0 \text{ V},  I_S = 2.7 \text{ A}$ (Note 2)		0.8	1.2	V

2. Pulse Test: Pulse Width < 300 $\mu$ s, Duty Cycle < 2.0%

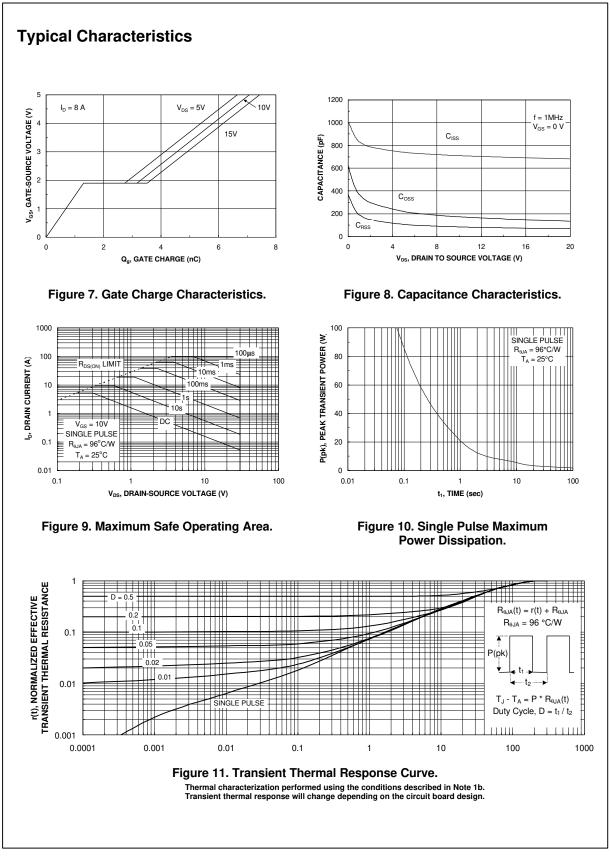
3. Maximum current is calculated as:

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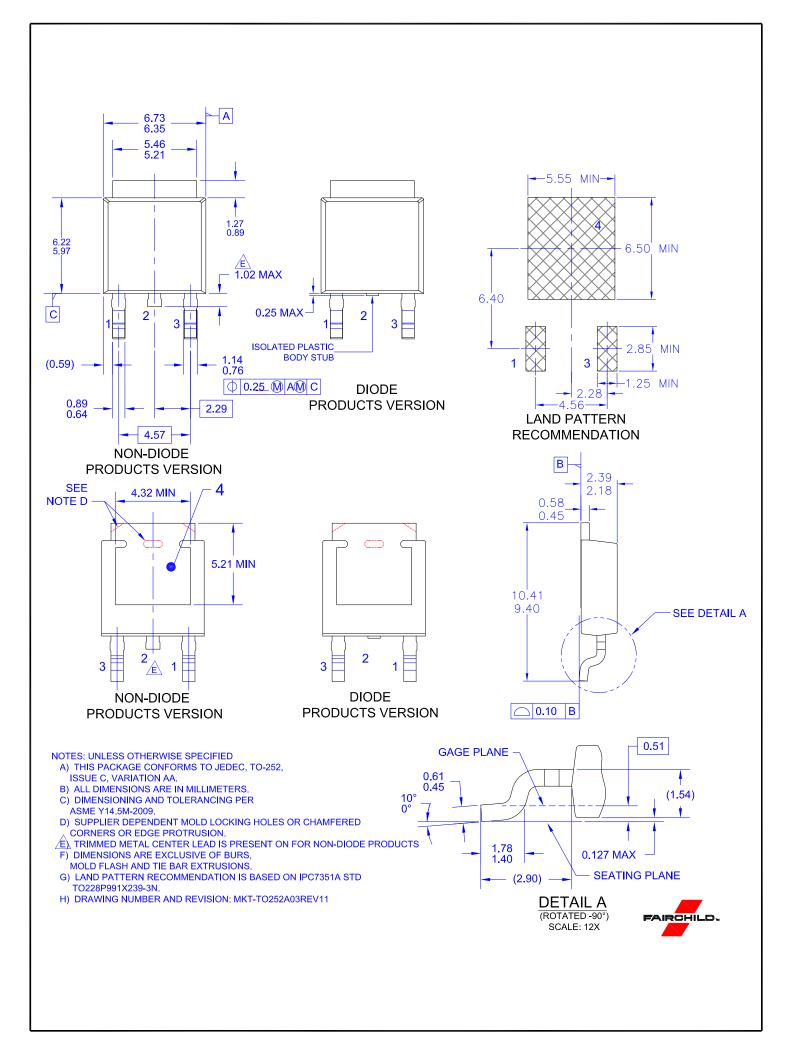
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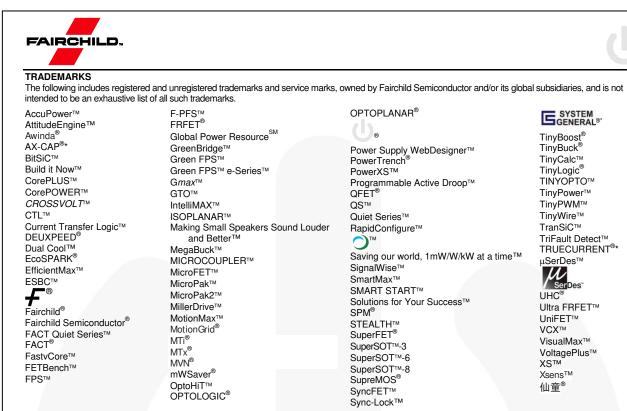


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